Docket No. P0284US-7

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

applicant:

LI et al.

Examiner: Tran

Serial No.

10/676,953

Group Art Unit: 2826

Filed: September 30, 2003

Title: LIGHT EMITTING DIODE WITH POROUS SIC SUBSTRATE AND METHOD

FOR FABRICATING

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

TRANSMITTAL FOR SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

Transmitted herewith is Supplemental Information Disclosure Statement for this application and a PTO Form 1449 citing the U.S patent references.

If any additional fee is required, the Commissioner is authorized to charge Deposit Account No. 11-1580. A duplicate of this transmittal is attached.

Dated: 6/15/05

Respectfully submitted,

Jayé G. Heybl

Registration No. 42,661 Attorney for Applicant

KOPPEL, JACOBS, PATRICK & HEYBL

555 St. Charles Drive, Suite 107 Thousand Oaks, California, 91360

Telephone: (805) 373-0060

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service first Class mail addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA, 22313 1

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Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

This certification is being made for this Supplemental Information Disclosure Statement. Applicants submit a copy of each of the non-U.S. patent references listed on the attached PTO-1449 (Modified) form for consideration by the Examiner.

I, the person signing below certify that:

- each item of information contained in the supplemental information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the supplemental information disclosure statement (37 C.F.R. § 1.97(e)(1)); or
- (b) no item of information contained in the supplemental information disclosure statement, to the knowledge of the person signing the certification after making reasonable inquiry, was known to any individual designated in § 1.56(c) more than three months prior to the filing of the statement. 37 C.F.R. § 1.97(e)(2).

This submission does not represent that a search has been made or that no better art exists and does not constitute an admission that each or all of the listed documents are material or constitute "prior art". If the Examiner applies any of the documents as prior art against any claim in the application and applicants determine that the cited documents do not constitute "prior art" under United States law, applicants reserve the right to present to the

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Marianne Middleton

Office the relevant facts and law regarding the appropriate status of such documents.

Respectfully submitted,

June 14, 2005

Registration No. 42,661

Attorney for Applicant

KOPPEL, JACOBS, PATRICK & HEYBL 555 St. Charles Drive, Suite 107 Thousand Oaks, California 91360 (805) 373-0060

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Date

FORM PTO-1449 (Modified) INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)									Docket No. P0284US-7			Application Number 10/676,953		
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Examiner Initial	Document Number							Date	Name	Class	Subclass	Filing Date If Appropriate		
	5	6	4	4	1	5	6	07/01/97	SUZUKI et al.	257	485			
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OTHER	DOCU								Title, Dat	e, Per	tinent I	ages,	Etc.	
	1	US 2001/010449 A1 (CHIU CHIEN-CHIA et al) AUGUST 2, 2001.												
	2	LAGOUBI, A. et al. "CONDITIONING OF N-SILICON BY PHOTOELECTROCHEMICAL ETCHING FOR PHOTOVOLTAIC APPLICATIONS" PROC. OF THE 11 ^{TR} E.C. PHOTOVOLTAIC SOLAR ENERGY CONFERENCE, OCTOBER 12, 1992-OCTOBER 16, 1992, pp. 250-253, XP008043956pp 252-253 Figure 8.												
	3	PATI	ENT AB	STRAC	TS OF	JAPA	N, 07	007179, 10-0	1-95, SANYO ELEC	TRIC CO LTD,	"LIGHT EMIT	TING ELEM	ENTZ"	
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